

WEST Search History

DATE: Tuesday, June 24, 2003

<u>Set Name</u>	<u>Query</u>	<u>Hit Count</u>	<u>Set Name</u>
side by side			result set
<i>DB=USPT,PGPB,JPAB,EPAB,DWPI,TDBD; PLUR=YES; OP=OR</i>			
L11	l2 and l6	4	L11
<i>DB=USPT; PLUR=YES; OP=OR</i>			
L10	5863677.pn.	1	L10
L9	5965327.pn.	1	L9
L8	6094256.pn.	1	L8
<i>DB=USPT,PGPB,JPAB,EPAB,DWPI,TDBD; PLUR=YES; OP=OR</i>			
L7	6558881	2	L7
L6	l3 and l5	6	L6
L5	angle adj4 (60 or 120)	28542	L5
L4	l1 and l2 and l3	19	L4
L3	photon\$4 adj4 lattice\$	192	L3
L2	rods	1062232	L2
L1	hexagon\$3	95369	L1

END OF SEARCH HISTORY

L5 ANSWER 2 OF 3 INSPEC COPYRIGHT 2003 IEE
AN 1997:5534821 INSPEC DN A9709-4255P-009; B9705-4320J-021
TI Photopumped laser operation of an oxide post GaAs-AlAs superlattice
photonic lattice.
AU Evans, P.W.; Wierer, J.J.; Holonyak, N., Jr. (Mater. Res. Lab., Illinois
Univ., Urbana, IL, USA)
SO Applied Physics Letters (3 March 1997) vol.70, no.9, p.1119-21. 4 refs.
Doc. No.: S0003-6951(97)01009-7
Published by: AIP
Price: CCCC 0003-6951/97/70(9)1119(3)\$10.00
CODEN: APPLAB ISSN: 0003-6951
SICI: 0003-6951(19970303)70:9L.1119:PLOO;1-C
DT Journal
TC Experimental
CY United States
LA English
AB Data are presented on the laser operation of photoexcited active
hexagonal photonic lattices consisting of a
GaAs-AlAs superlattice slab waveguide patterned with Zn-disordered AlGaAs
posts that are converted to oxide. The semiconductor-oxide-post
photonic lattice structure lases without the benefit of
cleaved edges or other reflecting interfaces owing to strong local optical
feedback provided by the high refractive index contrast between oxide
posts and the active GaAs-AlAs superlattice. As the pump area is increased
at constant pump power, the threshold intensity decreases as higher Q
modes in an effectively larger cavity are excited. Similar
hexagonal photonic lattices with nonoxidized
posts (disordered AlGaAs posts) operate as lasers, but only with the
assistance of cleaved edges and by shifting to longer wavelength. The
oxide post photonic lattice is compatible with
current-driven photonic lattice lasers or active
filters.
CC A4255P Lasing action in semiconductors; A7865J Optical properties of
nonmetallic thin films; B4320J Semiconductor lasers; B2530C Semiconductor
superlattices, quantum wells and related structures
CT ALUMINIUM COMPOUNDS; GALLIUM ARSENIDE; III-V SEMICONDUCTORS; LASER
FEEDBACK; OPTICAL PUMPING; PHOTONIC BAND GAP; QUANTUM WELL LASERS;
REFRACTIVE INDEX; SEMICONDUCTOR SUPERLATTICES; WAVEGUIDE LASERS
ST oxide post GaAs-AlAs superlattice photonic lattice; photopumped
laser operation; photoexcited active hexagonal photonic lattices
; GaAs-AlAs superlattice slab waveguide; Zn-disordered AlGaAs posts;
semiconductor-oxide-post photonic lattice structure; strong local
optical feedback pro; high refractive index contrast; pump area; constant
pump power; threshold intensity; higher Q modes; effectively larger
cavity; hexagonal photonic lattices; nonoxidized posts;
disordered AlGaAs posts; cleaved edges; longer wavelengt; oxide post
photonic lattice; GaAs-AlAs; AlGaAs:Zn
CHI GaAs-AlAs int, AlAs int, GaAs int, Al int, As int, Ga int, AlAs bin, GaAs
bin, Al bin, As bin, Ga bin; AlGaAs:Zn int, AlGaAs int, Al int, As int, Ga
int, Zn int, AlGaAs:Zn ss, AlGaAs ss, Al ss, As ss, Ga ss, Zn ss, Zn el,
Zn dop
ET Al*As*Ga; Al sy 3; sy 3; As sy 3; Ga sy 3; GaAs; Ga cp; cp; As cp; AlAs;
Al cp; GaAs-AlAs; Zn; AlGaAs; V; Al*As*Ga*Zn; Al sy 4; sy 4; As sy 4; Ga
sy 4; Zn sy 4; AlGaAs:Zn; Zn doping; doped materials; Al*As; Al sy 2; sy
2; As sy 2; As*Ga; Ga sy 2; Al; As; Ga

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L5 ANSWER 3 OF 3 INSPEC COPYRIGHT 2003 IEE
AN 1993:4317869 INSPEC DN A9304-7820D-003
TI Photonic band gaps in two-dimensional square and hexagonal
lattices.
AU Villeneuve, P.R.; Piche, M. (Dept. de Phys., Laval Univ., Que., Canada)
SO Physical Review B (Condensed Matter) (15 Aug. 1992) vol.46, no.8,
p.4969-72. 13 refs.

CODEN: PRBMDO ISSN: 0163-1829
DT Journal
TC Theoretical
CY United States
LA English
AB Two-dimensional square and **hexagonal lattices** exhibit photonic band gaps common to s- and p- polarized waves. These gaps occur from an overlap of the gaps between the first and second p bands and higher s bands. A dielectric structure with a hexagonal lattice of air holes requires a lower index contrast to generate a band gap and gives rise to larger gaps than a square lattice. Furthermore, square and **hexagonal lattices** of dielectric rods in air do not give rise to band gaps even when asymmetry is introduced to lift the degeneracies.
CC A7820D Optical constants and parameters
CT ENERGY GAP; OPTICAL CONSTANTS
ST photonic band gaps; 2D square lattices; 2D **hexagonal lattices**; polarized waves; p bands; s bands; dielectric structure; dielectric rods; degeneracies
ET D

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L6 ANSWER 1 OF 3 CA COPYRIGHT 2003 ACS
AN 136:61145 CA
TI Effects of shapes and orientations of scatterers and lattice symmetries on the photonic band gap in two-dimensional photonic crystals
AU Wang, Rongzhou; Wang, Xue-Hua; Gu, Ben-Yuan; Yang, Guo-Zhen
CS Institute of Physics, Chinese Academy of Science, Beijing, 100080, Peop. Rep. China
SO Journal of Applied Physics (2001), 90(9), 4307-4313
CODEN: JAPIAU; ISSN: 0021-8979
PB American Institute of Physics
DT Journal
LA English
CC 73-11 (Optical, Electron, and Mass Spectroscopy and Other Related Properties)
AB The photonic band structures of 2-dimensional photonic crystals consisting of lattices with different symmetries and scatterers of various shapes, orientations, and sizes are studied numerically. Specifically, 4 types of lattices (triangular, hexagonal, square, and rectangular) and 5 different shapes of scatterers (hexagon, circle, square, rectangle, and ellipse) are considered. The scatterers are either dielec. rods in air, or air rods in dielec. media. The lattice symmetry and all these properties of the scatterers can affect the band gap size. Given a lattice symmetry, the largest abs. photonic band gap is achieved by selecting a scatterer of the same symmetry; e.g., hexagonal rods in triangular or honeycomb lattices, square rods in square lattices, and rectangular rods in rectangular lattices. The band gap can be further maximized by adjusting the orientation and size of the scatterers; but no simple, systematic rules can be drawn.
ST shape orientation scatterer photonic band gap
IT Band structure
Photonic crystals
Photonics
(effects of shapes and orientations of scatterers and lattice symmetries on photonic band gap in two-dimensional photonic crystals)
IT Band gap
(photonic; effects of shapes and orientations of scatterers and lattice symmetries on photonic band gap in two-dimensional photonic crystals)
RE.CNT 23 THERE ARE 23 CITED REFERENCES AVAILABLE FOR THIS RECORD
RE
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(20) Villeneuve, P; Phys Rev B 1992, V46, P4973
(21) Wang, X; Phys Rev B 1999, V60, P11417 CA
(22) Yablonovitch, E; Phys Rev Lett 1987, V58, P2059 CA

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L6 ANSWER 2 OF 3 CA COPYRIGHT 2003 ACS
AN 127:323946 CA
TI Experimental demonstration of complete photonic band gap in graphite
structure
AU Gadot, F.; Chelnokov, A.; De Lustrac, A.; Crozat, P.; Lourtioz, J.-M.;
Cassagne, D.; Jouanin, C.
CS Institut d'Electronique Fondamentale, Universite de Paris-Sud, Orsay
Cedex, 91405, Fr.
SO Applied Physics Letters (1997), 71(13), 1780-1782
CODEN: APPLAB; ISSN: 0003-6951
PB American Institute of Physics
DT Journal
LA English
CC 73-3 (Optical, Electron, and Mass Spectroscopy and Other Related
Properties)
AB We exptl. demonstrate the existence of complete photonic band gap in
graphite-type photonic crystals, thereby confirming theor. predictions
reported in previous studies. Expts. were performed at microwave
frequencies from 27 to 75 GHz using two-dimensional **hexagonal**
lattices of alumina rods. Transmission spectra measured for E
(TM) and H (TE) polarizations and for different orientations of the
two-dimensional lattice are in excellent agreement with numerical calcns.
The complete photonic band gap results from the overlap of E7 and H5
forbidden bands. Attenuations larger than 30 dB are measured for
structures comprised of only four rows of alumina rods.
ST microwave photonic band gap hexagonal lattice; alumina hexagonal
lattice photonic band gap
IT Band structure
(microwave photonic band gap in hexagonal lattice of alumina rods)
IT Band gap
(photonic; microwave photonic band gap in hexagonal lattice of alumina
rods)
IT Microwave spectra
(polarized; microwave photonic band gap in hexagonal lattice of alumina
rods)
IT 1344-28-1, Alumina, properties
RL: PRP (Properties)
(microwave photonic band gap in hexagonal lattice of alumina rods)

L6 ANSWER 3 OF 3 CA COPYRIGHT 2003 ACS
AN 126:310137 CA
TI Photopumped laser operation of an oxide post GaAs-AlAs superlattice
photonic lattice
AU Evans, P. W.; Wierer, J. J.; Holonyak, N., Jr.
CS Elec. Eng. Res. Lab., Univ. Illinois Urbana-Champaign, Urbana, IL, 61801,
USA
SO Applied Physics Letters (1997), 70(9), 1119-1121
CODEN: APPLAB; ISSN: 0003-6951
PB American Institute of Physics
DT Journal
LA English
CC 73-10 (Optical, Electron, and Mass Spectroscopy and Other Related
Properties)
AB Data are presented on the laser operation of photoexcited active
hexagonal photonic lattices consisting of a
GaAs-AlAs superlattice slab waveguide patterned with Zn-disordered AlGaAs
posts that are converted to oxide. The semiconductor-oxide-post
photonic lattice structure lases without the benefit of
cleaved edges or other reflecting interfaces owing to strong local optical
feedback provided by the high refractive index contrast between oxide
posts and the active GaAs-AlAs superlattice. As the pump area is
increased at const. pump power, the threshold intensity decreases as

DUPPLICATED

higher Q modes in an effectively larger cavity are excited. Similar hexagonal photonic lattices with nonoxidized posts (disordered AlGaAs posts) operate as lasers, but only with the assistance of cleaved edges and by shifting to longer wavelength. The oxide post photonic lattice is compatible with current-driven photonic lattice lasers or active filters.

ST aluminum gallium arsenide oxide post laser
IT Lasers
Optical waveguides
(photopumped laser operation of oxide post GaAs-AlAs superlattice photonic lattice)
IT 106070-10-4, Aluminum gallium arsenide (Al_{0.7}Ga_{0.3}As)
RL: DEV (Device component use); USES (Uses)
(photopumped laser operation of oxide post GaAs-AlAs superlattice photonic lattice)
IT 7440-66-6, Zinc, uses
RL: DEV (Device component use); MOA (Modifier or additive use); USES (Uses)
(photopumped laser operation of oxide post GaAs-AlAs superlattice photonic lattice)

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(FILE 'HOME' ENTERED AT 18:21:16 ON 24 JUN 2003)

FILE 'INSPEC' ENTERED AT 18:21:31 ON 24 JUN 2003
L1 0 HEXAGONAL ADJ LATTICES
L2 379 HEXAGONAL (2A) LATTICES
L3 1204 4 (2A) LATTICE
L4 235 PHOTONIC (2A) LATTICE#
L5 3 L2 AND L4

FILE 'CA' ENTERED AT 18:26:30 ON 24 JUN 2003
L6 3 L5

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(FILE 'HOME' ENTERED AT 18:21:16 ON 24 JUN 2003)

FILE 'INSPEC' ENTERED AT 18:21:31 ON 24 JUN 2003
L1 0 HEXAGONAL ADJ LATTICES
L2 379 HEXAGONAL (2A)LATTICES
L3 1204 4 (2A)LATTICE
L4 235 PHOTONIC (2A)LATTICE#
L5 3 L2 AND L4

FILE 'CA' ENTERED AT 18:26:30 ON 24 JUN 2003
L6 3 L5
L7 3 L6
L8 44274 RODS

FILE 'CA' ENTERED AT 18:33:44 ON 24 JUN 2003
L9 44274 RODS
L10 181 L4
L11 22 L10 AND L9
L12 58763 HEXAGONAL
L13 4 L11 AND L12
SET SMA OFF
SEL RAN.CA(21) L13 1
SET SMA LOGIN
L14 1 S E1

FILE 'STNGUIDE' ENTERED AT 18:35:42 ON 24 JUN 2003
L15 0 RODS